



DUAL SURFACE MOUNT NPN/PNP TRANSISTORS (COMPLIMENTARY)

This device contains two electrically-isolated complimentary pair (NPN and PNP) general-purpose transistors. This device is ideal for portable applications where board space is at a premium.

FEATURES

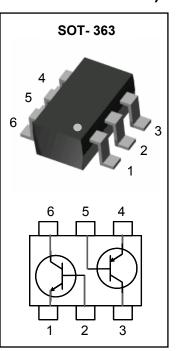
- Electrically-Isolated Complimentary Transistor Pairs
- Lead free in comply with EU RoHS 2002/95/EC directives.
- Green molding compound as per IEC61249 Std. . (Halogen Free)

APPLICATIONS

- General Purpose Amplifier Applications
- Hand-Held Computers, PDAs

Device Marking Code: 47P

MAXIMUM RATINGS - NPN



 $T_J = 25$ °C Unless otherwise noted

Rating	Symbol	Value	Units
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage Voltage	V _{EBO}	6.0	V
Collector Current	I _C	100	mA

MAXIMUM RATINGS - PNP

 T_J = 25°C Unless otherwise noted

Rating	Symbol	Value	Units
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage Voltage	V _{EBO}	-5.0	V
Collector Current	I _C	-100	mA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 1)	P _D	200	mW
Operating Junction Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Thermal Resistance, Junction to Ambient (Note 1)	R _{thja}	556	°C/W

Note 1. FR-4 board 70 x 60 x 1mm with minimum recommended pad layout





NPN ELECTRICAL CHARACTERISTICS (Note 2)

T_J = 25°C Unless otherwise noted

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Collector-Emitter Breakdown Voltag	V _{(BR)CEO}	I _C = 10mA	45	-	-	V
Collector-Emitter Breakdown Voltag	V _{(BR)CES}	I _C = 10uA, V _{EB} = 0	50	-	-	V
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C = 10uA	50	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	I _E = 1.0uA	6.0	-	-	V
Collector Cutoff Current	I _{CBO}	Von= 30V I == 0	-	-	15	nA
Collector Cutoff Current	ICBO	V_{CB} = 30V, I_{E} = 0 T_{J} =150°C	-	-	5	uA
Emitter Cutoff Current	I _{EBO}	V _{EB} = 5V, I _C = 0	-	-	100	nA
DC Current Gain	h _{FE}	V _{CE} = 5V, I c= 2.0mA	200	-	450	-
Collector-Emitter Saturation Voltage	VCE(SAT)	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$	-	-	0.1	V
Concetor-Emitter Gataration Voltage		I _C = 100mA, I _B = 5mA	-	-	0.4	V
Base-Emitter Saturation Voltage	V _{BE(SAT)}	I _C = 10mA, I _B = 0.5mA	-	0.75	-	V
Base-Emitter Voltage	V_{BE}	V _{CE} = 5V, I c= 2.0mA	0.58	-	0.7	V
Gain-Bandwidth Product	f _T	V _{CE} = 5V, I c= 10mA f = 100MHz	100	-	-	MHz
Collector-Base Capacitance	Ссво	V _{CB} = 10V, f =1.0MHz	-	-	1.5	pF
Emitter-Base Capacitance	Сево	V _{EB} = 0.5V, f =1.0MHz	-	7	1	pF

PNP ELECTRICAL CHARACTERISTICS (Note 2)

T = 25°C Unless otherwise noted

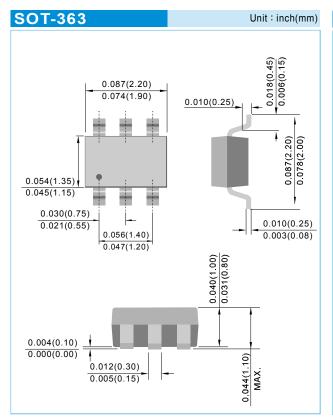
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = -10mA	-45	-	-	V
Collector-Emitter Breakdown Voltage	V _{(BR)CES}	I _C = -10uA, V _{EB} = 0	-50	-	-	V
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C = -10uA	-50	-	-	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E = -1.0uA	-5.0	-	-	V
Collector Cutoff Current	lan a	Van= 20V L== 0	-	-	-15	nA
Collector Cutoff Current	bllector Cutoff Current I_{CBO} V_{CB} = -30V, I_{E} = 0 T_{J} =150°C		-	-	-4.0	uA
Emitter Cutoff Current	I _{EBO}	V _{EB} = -5V, I _C = 0	-	-	-100	nA
DC Current Gain	h _{FE}	V _{CE} = -5V, I c= -2.0mA	200	-	475	
Collector-Emitter Saturation Voltage	VCE(SAT)	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$	-	-	-0.3	V
Collector-Emitter Saturation Voltage		$I_C = -100 \text{mA}, I_B = -5 \text{mA}$	-	-	-0.65	V
Base-Emitter Saturation Voltage	V _{BE(SAT)}	I _C = -10mA, I _B = -0.5mA	-	-0.7	-	V
Base-Emitter Voltage	V_{BE}	V _{CE} = -5V, I c= -2.0mA	-0.6	-	-0.75	V
Gain-Bandwidth Product	f _T	V _{CE} = -5V, I c= -10mA f = 100MHz	100	•	-	MHz
Collector-Base Capacitance	Ссво	V _{CB} = -10V, f =1.0MHz	-	-	4.5	pF
Emitter-Base Capacitance	Сево	V _{EB} = -0.5V, f =1.0MHz	-	11	-	pF

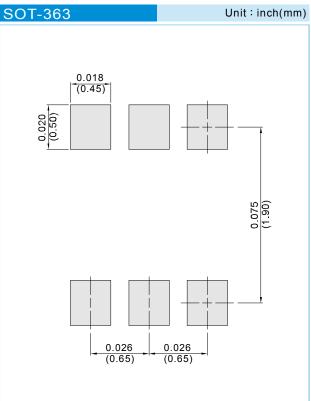
Note 2. Short duration test pulse used to minimize self-heating





PACKAGE LAYOUT AND SUGGESTED PAD DIMENSIONS





ORDERING INFORMATION

BC847BPN T/R7 - 3,000 units per 7 inch reel BC847BPN T/R13 -10,000 units per 13 inch reel





BC847BPN

Part No_packing code_Version

BC847BPN_R1_00001 BC847BPN_R2_00001

For example:



Packing Code XX			Version Code XXXXX			
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	Α	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	В	13"	2			
Tube Packing (T/P)	Т	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			

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BC847BPN

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